PD-94689D

# International Rectifier

# HYBRID - HIGH RELIABILITY RADIATION TOLERANT DC-DC CONVERTER

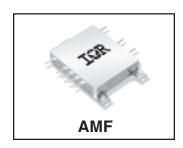
## **Description**

The AMF28XXS series of DC-DC converter modules has been specifically designed for operation in moderate radiation environments supplementing the higher radiation performance available in the International Rectifier ART, ARH and G-Series converters. Environments presented to space vehicles operating in low earth orbits, launch boosters, orbiting space stations and similar applications requiring a low power, high performance converter with moderate radiation hardness performance will be optimally served by the AMF28XXS Series.

The physical configuration of the AMF28XXS series permits mounting directly to a heat dissipation surface without the necessity of signal leads penetrating the heat sink surface. This package configuration permits greater independence in mounting and more mechanical security than traditional packages. International Rectifier's rugged ceramic seal pins are used exclusively in the package thereby assuring long term hermeticity.

The AMF28XXS has been designed for high density using chip and wire hybrid technology that complies with the class H requirements of MIL-PRF-38534. Manufactured in a facility fully qualified to MIL-PRF-38534, these converters are fabricated utilizing DLA qualified processes. For available screening options, refer to device screening table in the data sheet. Applicable generic lot qualification test data including radiation performance can be made available on request. Consult IR San Jose for special requirements.

# AMF28XXS SERIES 28V Input, Single Output



#### **Features**

- 12Watts Output Power
- Available in 3.3, 5, 7.5, 12 and 15Volt Outputs
- 16 40VDC Input Range (28VDC Nominal)
- Low Input/Output Noise
- Total Ionizing Dose > 25KRads (Si)
- SEE Hardened to LET up to 60MeV.cm²/mg
- -55°C to +125°C Operating Range
- Indefinite Short Circuit Protection
- Flexible Mounting
- High Power Density
- Fully Isolated Input to Output and to Case
- Complimentary EMI Filter Available
- Synchronizable From An External Source
- Electrical Performance Similar to AHF28XXS Series
- Standard Microcircuit Drawings Available

# **Specifications**

Absolute Maximum R	atings	Recommended Operating Conditions			
Input Voltage range	-0.5V to +50VDC	Input Voltage range	+16V to +40VDC		
Soldering temperature	300°C for 10 seconds	Output Power	Less than or equal to 12W		
Storage case temperature	-65°C to +135°C	Operating case temperature	-55°C to +125°C		

# $\textbf{Static Characteristics} \ \ \text{-55}^{\circ}\text{C} \leq \text{T}_{CASE} \leq \text{+125}^{\circ}\text{C}, \ V_{IN} = 28 \\ V_{DC} \pm 5\%, \ C_{L} = 0, \ unless \ otherwise \ specified.$

Parameter		Group A Subgroups	Test Conditions	Min	Nom	Max	Unit
		Subgroups	rest Conditions	16	28	40	V
Input Voltage				16	28	40	V
Output Voltage			Vin = 28 Volts, 0% load				
	803R3S	1		3.25	3.30	3.35	
AM	F2805S	1		4.95	5.00	5.05	
AMF2	807R5S	1		6.97	7.50	7.58	
	F2812S	1		11.88	12.00	12.12	
AM	F2815S	1		14.85	15.00	15.15	
****		0.0		0.00		0.40	V
	803R3S	2, 3		3.20		3.40	
	F2805S	2, 3		4.90		5.10	
	807R5S	2, 3		7.35		7.65	
	F2812S	2, 3		11.76		12.24	
AM	F2815S	2, 3		14.70		15.30	
Output Current 1			Vin = 16, 28, 40 Volts				
AMF2	803R3S	1, 2, 3	, , , , , , , , , , , , , , , , , , , ,	0		3000	
	F2805S	1, 2, 3		0		2400	
	807R5S	1, 2, 3		0		1600	mA
	F2812S	1, 2, 3		0		1000	
	F2815S	1, 2, 3		0		800	
Output Power <sup>1</sup>			Vin = 16, 28, and 40 Vdc				
	000000	1, 2, 3	VIII = 10, 28, and 40 vuc			10	w
	803R3S	1, 2, 3				12	VV
A	I Others	1, 2, 3				12	
Output Ripple Voltage	2	1, 2, 3	Vin = 16, 28, 40 Volts,		25	60	$mV_{PP}$
			BW = 20 Hz to 2 MHz				
Output Voltage							
Regulation			V <sub>in</sub> = 16, 28, 40 Volts				
Line AMF2	803R3S	1, 2, 3	lout = 0%, 50%, and 100%		10	25	
AM	F2805S	1, 2, 3	max		10	25	
AMF2	807R5S	1, 2, 3			10	50	
AM	F2812S	1, 2, 3			10	50	mV
AM	F2815S	1, 2, 3			10	50	
	<b>A</b> 11	1 0 0			10	F0	
Load	All	1, 2, 3			10	50	

For Notes to Specifications, refer to page 5

 $\textbf{Static Characteristics} \text{ (Continued)} \quad -55^{\circ}\text{C} \leq \text{T}_{CASE} \leq +125^{\circ}\text{C}, \text{ V}_{IN} = 28 \text{ V}_{DC} \pm 5\%, \text{ CL} = 0, \text{ unless otherwise specified.}$ 

Parameter	Group A Subgroups	Test Conditions	Min	Nom	Max	Unit
Input Current No Load	1, 2, 3	Vin = 28V, lout = 0, Inhibit (pin 1) = open (AMF2812S and AMF2815S) (All other Models)		30 20	50 30	mA
Inhibit	1, 2, 3	Inhibit (pin 1) shorted to input return (pin 7) (All Models)		8.0	12	
Input Ripple Current	1, 2, 3	Vin = 16, 28, 40 Volts, 100% load, BW = 20 Hz to 2 MHz		20	50	mA <sub>PP</sub>
Efficiency  AMF2803R3S	1 1, 3 1, 3 1, 3 1, 3 2, 3 2 2 2 2	100% load	71 76 77 78 78 70 72 73 75 75			%
Isolation	1	Input to output or any pin to case (except pin 6) at 500Vdc	100			MΩ
Capacitive Load <sup>3, 4</sup> AMF2803R3S AMF2805S AMF2807R5S AMF2812S AMF2815S	4 4 4 4 4	No effect on dc performance			500 500 300 200 200	μF
Short Circuit Power Dissipation	1, 2, 3	AMF2803R3S All other Models			7.0 6.0	w
Short Circuit Recovery 4	4, 5, 6	0% load to 100% Load			20	ms
Switching Frequency	4, 5, 6	100% load	500	550	600	KHz
мтвғ		MIL-HDBK-217F SF @ Tc = 35°C	750			Khr
Weight					36	g

For Notes to Specifications, refer to page 5

 $\textbf{Dynamic Characteristics} \ \ \text{-}55^{\circ}\text{C} \leq \text{T}_{CASE} \leq \text{+}125^{\circ}\text{C}, \ \text{V}_{IN} = 28 \ \text{V}_{DC} \pm 5\%, \ \text{CL} = 0, \ \text{unless otherwise specified}.$ 

Parameter	Group A Subgroups	Test Conditions	Min	Nom	Max	Unit
Synchronization Input  Frequency Range Pulse Amplitude, Hi <sup>4</sup> Pulse Amplitude, Lo <sup>4</sup> Pulse Rise time <sup>4</sup> Pulse Duty Cycle <sup>4</sup>	4, 5, 6		500 2.5 -0.5		700 10 0.8 100 80	KHz V V ns %
Output Response To Step Transient Load Changes  All  AMF2803R3S  AMF2805S  AMF2807R5S  AMF2812S  AMF2815S	4, 5, 6 4, 5, 6 4, 5, 6 4, 5, 6 4, 5, 6 4, 5, 6	Load step 50% ⇔ 100%  Load step 0% ⇔ 50%	-300 -400 -500 -750 -750 -750		+300 +400 +500 +750 +750 +750	mVpk
Recovery Time, Step Transient Load Changes 5, 6 AMF2803R3S AMF2805S AMF2807R5S AMF2812S AMF2815S	4, 5, 6 4, 5, 6 4, 5, 6 4, 5, 6 4, 5, 6 4, 5, 6	Load step 50% ⇔ 100%  Load step 0% ⇔ 50%			70 70 100 100 100	μs ms
Output Response Transient Step Line Changes 4,7 AMF2803R3S AMF2805S AMF2807R5S AMF2812S AMF2815S Recovery Time Transient Step	4, 5, 6 4, 5, 6 4, 5, 6 4, 5, 6 4, 5, 6	Input step 16 ⇔ 40Vdc 100% Load  Input step 16 ⇔ 40Vdc, 100%	-500 -500 -1200 -1500 -1500		+500 +500 +1200 +1500 +1500	mVpk
Line Changes 4.7  Turn On Overshoot 8  AMF2803R3S  AMF2805S  AMF2807R5S  AMF2812S  AMF2815S	4, 5, 6 4, 5, 6 4, 5, 6 4, 5, 6 4, 5, 6 4, 5, 6	load  0% load to 100% load			400 600 600 600 750	μs mVpk
Turn On Delay <sup>8</sup>	4, 5, 6	0% load to 100% load			20	ms

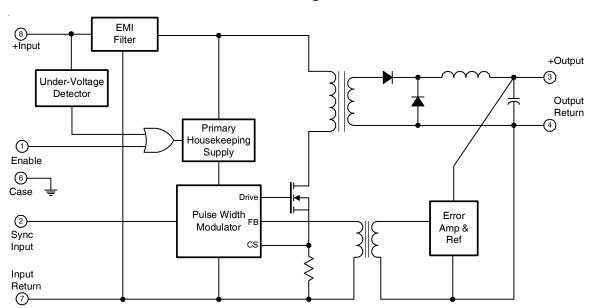
For Notes to Specifications, refer to page 5

# AMF28XXS Series (28V Input, Single Output)

#### Notes to Specifications

- 1 Parameter guaranteed by line and load regulation tests.
- 2 Bandwidth guaranteed by design. Tested for 20Hz to 2.0MHz.
- 3 Capacitive load may be any value from 0 to the maximum limit without compromising dc performance. A capacitive load in excess of the maximum limit will not disturb loop stability but may interfere with the operation of the load fault detection circuitry, appearing as a short circuit during turn on.
- 4 Parameter shall be tested as part of design characterization and after design or process changes. Therefore this Parameters shall be guaranteed to the limit specified.
- 5 Load step transition time between 2.0 and 10 microseconds.
- 6 Recovery time is measured from the initiation of the transient to where VouT has returned to within ±1 % of VouT at 50 percent load.
- 7 Input step transition time between 1.0 and 10 microseconds. Parameter guaranteed by design but not 100% tested.
- 8 Turn on delay time measurement is for either a step application of power at the input or the removal of a ground signal from the inhibit pin while power is applied to the input.

## **Block Diagram**



# **Application Information**

### Inhibit Function (Enable)

Connecting the enable input (Pin 1) to input common (Pin 7) will cause the converter to shut down. It is recommended that the enable pin be driven by an open collector device capable of sinking at least 400  $\mu A$  of current. The open circuit voltage of the enable input is 10 +1.0 VDC.

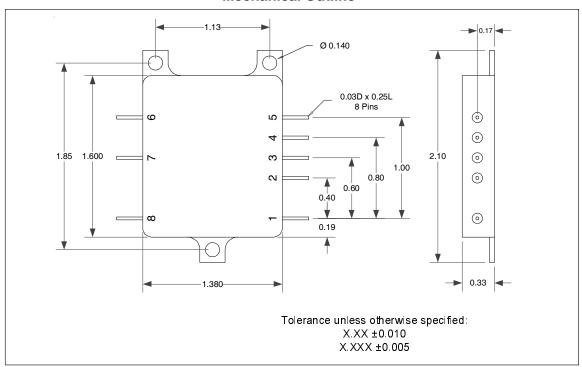
#### **EMI Filter**

An optional EMI filter is available (AFH461) that will reduce the input ripple current to levels below the limits imposed by MIL-STD-461 CE03.

### **Device Synchronization**

When multiple DC-DC converters are utilized in a single system, significant low frequency noise may be generated due to a small difference in the switching frequency of the converters (beat frequency noise). Because of the low frequency nature of this noise (typically less than 10 KHz), it is difficult to filter out and may interfere with proper operation of sensitive systems (communication, radar or telemetry). Interenational Rectifier provides synchronization of multiple AMF type converters to match switching frequency of the converter to the frequency of the system clock, thus eliminating this type of noise.

# **Mechanical Outline**



# **Pin Designation**

Pin #	Designation			
1	Enable			
2	Sync. Input			
3	+ Output			
4	Output Return			
5	NC			
6	Case Ground			
7	Input Return			
8	+ Input			

# **Standard Microcircuit Drawing Equivalance Table**

Standard Microcircuit	IR Standard
Drawing Number	Part Number
5962-04252	AMF2805S
5962-04253	AMF2812S
5962-04254	AMF2815S
5962-10223	AMF2803R3S

# **Radiation Specification**

Parameter	Condition	Min	Тур	Max	Unit
Total Ionizing Dose	MIL-STD-883, Method 1019.4 Operating bias applied during exposure	25	_	_	KRads (Si)
Heavy Ion (Single event effects)	BNL Dual Van de Graf Generator	60	_	_	MeV •cm² /mg

International Rectifier currently does not have a DLA certified Radiation Hardness Assurance Program.

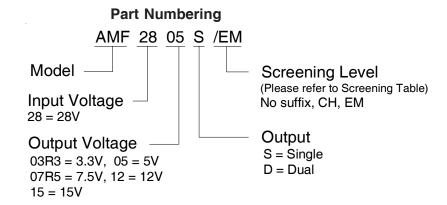
# **Device Screening**

Requirement	MIL-STD-883 Method	No Suffix ②	CH ②	ЕМ
Temperature Range	_	-55°C to +125°C	-55°C to +125°C	-55°C to +85°C
Element Evaluation	MIL-PRF-38534	Class H	Class H	N/A
Non-Destructive Bond Pull	2023	N/A	N/A	N/A
Internal Visual	2017	Yes	Yes	0
Temperature Cycle	1010	Cond C	Cond C	Cond C
Constant Acceleration	2001, Y1 Axis	3000 Gs	3000 Gs	3000 Gs
PIND	2020	Cond A	Cond A	N/A
Burn-In	1015	320 hrs @ 125°C	320 hrs @ 125°C	48 hrs @ 125°C
Dum-m	1015	(2 x 160hrs)	(2 x 160hrs)	
Final Electrical	MIL-PRF-38534	-55°C, +25°C,	-55°C, +25°C,	-55°C, +25°C,
( Group A )	& Specification	+125°C	+125°C	+85°C
PDA	MIL-PRF-38534	2%	2%	N/A
Seal, Fine and Gross	1014	Cond A, C	Cond A, C	Cond A
Radiographic	2012	Yes	Yes	N/A
External Visual	2009	Yes	Yes	0

#### Notes:

- ① Best commercial practice.
- ② Device with '/CH' suffix is a DLA class H compliant without radiation performance. No suffix is a radiation rated device but not available as a DLA qualified SMD per MIL-PRF-38534.

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